

4.8W, Wide input, isolated & regulated dual output, IGBT dedicated DC-DC converter



Patent Protection RoHS

FEATURES

- 2:1 wide input voltage range
- Efficiency up to 85%
- Up to 3KVDC isolation
- Short circuit protection
- Output over-voltage protection
- Operating temperature range:-40°C to +85°C
- Industry standard pin-out
- IGBT dedicated regulated DC-DC converter

QAW series are designed for the IGBT driver, offer 4.8W of output, with output over-voltage protection and short-circuit protection. General application includes:

- Universal converter
- AC servo drive system
- Electric welding machine
- Uninterruptible power supply (UPS)

Selection	Guide					
	Inp	out	Ou	tput	Efficiency	Max.
Part No.	Input Voltage (VDC)	Input Current (mA,Typ) Full Load/No Load	Output Voltage (VDC)+Vo/-Vo	Output Current (mA)+lo/-lo	(%, Min ./Typ) @ Full Load	Capacitive Load (µF)
QAW01	12(9-18)	471/16	+15/-9	±200/±10	85	1000
QAW02	24(18-36)	235/8	+15/-9	±200/±10	85	1000

Input Specification	ns				
ltem	Operating Conditions	Min.	Тур.	Max.	Unit
Input \ (alterna	12VDC input	-0.7		25	
Input Voltage	24VDC input	-0.7		50	VDC
	12VDC input	-		9	VDC
Starting Voltage	24VDC input	-		18	
Input Filter			Capac	itor filter	

ltem	Operating Conditions	Min.	Тур.	Max.	Unit	
Output Power	Main output(+15V output)	0.24		4.8	W	
0. to . t) / . the set of a summer .	Supplement output(-9V output)		±1	±2	2	
Output Voltage Accuracy	Full load, Input voltage from low to high		±3	±5	%	
Line Regulation	Input voltage varies by ±1%		±0.2	±0.5	~ %	
Load Regulation	5% to 100% load		±0.5	±l		
Transient Recovery Time			0.5	2	μs	
Transient Response Deviation	25% load step change		±2.5	±5	%	
Temperature Drift Coefficient	100% load			±0.03	%/ ℃	
Ripple & Noise*	20MHz bandwidth		100	200	mVp-p	
Output Over-voltage Protection		110	120	140	% Vo	
Output Short Circuit Protection	Input voltage range		Continuous, self-recovery		ry	

General Specification	S				
ltem	Operating Conditions	Min.	Тур.	Max.	Unit

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DC/DC Converter for IGBT Driver **QAW** Series

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MTBF	MIL-HDFK-217F@25°C	1000			K hours
Switching frequency	100% load, nominal input voltage		300		KHz
Storage humidity	Non-condensing	5		95	%RH
Casing Temperature Rise	Τα=25 ℃		30	40	
Lead Temperature	Welding spot is 1.5mm away from the casing, 10 seconds			300	
Storage Temperature		-55		125	- °C
Operating Temperature	Power derating \ge 71 °C , (see Fig. 1)	-40	_	85	
Isolation Capacitance	Input-output, 100KHz/0.1V		100		pF
Isolation Resistance	Input-output, Isolation voltage 500VDC	1000			MΩ
Isolation Voltage	Input-output, with the test time of 1 minute and the leak current lower than 1mA	3000	-		VDC

Physical Specificatio	Physical Specifications	
Casing Material	Black flame-retardant and heat-resistant plastic (UL94-V0)	
Package Dimensions	31.60*20.30*10.20 mm	
Weight	14g (Typ.)	
Cooling Method	Free air convection	

EMC	Specifications			
EMI	Conducted Disturbance	CISPR22/EN55022	CLASS A (see Fig. 4- $\ensuremath{\textcircled{2}}$ for recommended circuit)	
LIVII	Radiated Emission	CISPR22/EN55022	CLASS A (see Fig. 4-2) for recommended circuit)	
	Electrostatic Discharge	IEC/EN61000-4-2	Contact ±4KV	perf. Criteria B
	Radiation Immunity	IEC/EN61000-4-3	10V/m	perf. Criteria A
	EFT	IEC/EN61000-4-4	±2KV (see Fig. 4-1) for recommended circuit)	perf. Criteria B
EMS	Surge Immunity	IEC/EN61000-4-5	±2KV (see Fig. 4-1) for recommended circuit)	perf. Criteria B
	Conducted disturbance Immunity	IEC/EN61000-4-6	3 Vr.m.s	perf. Criteria A
	Immunities of voltage dip, voltage drop and short interruption	IEC/EN61000-4-29	0%-70%	perf. Criteria B

Product Characteristic Curve

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Efficiency Vs Input Voltage (Full Load) 100 95 Efficiency(%) 8 28 06 QAW01 75 70 9 11 17 18 13 15 Input Voltage(V)

Efficiency Vs Output Load(Vin=Vin-nominal) 100 90 QAW01 80 Efficiency(%) 70 60 50 40 30 5 10 30 40 50 60 70 80 20 90 100 Output Power Percentage(%)

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Design Reference

1. Typical application

All the IGBT driver of this series are tested according to the recommended circuit (see Fig. 2) before delivery. If it is required to further reduce input and output ripple, properly increase the input & output of additional capacitors Cin and Cout or select capacitors of low equivalent impedance provided that the capacitance is no larger than the max. capacitive load of the product.



1. Typical application



2. EMC solution-recommended circuit(QAW01)



Vin	12V/24V
Cin	100µF
Cout	100µF

C1	100uF/63V(Electrolytic capacitor)
C2 /C4	100uF/35V(Electrolytic capacitor)
C3/C5	10uF/25V(Ceramic capacitor)

Application Notes

The wire between the converter and IGBT driver must as short as possible.
External filter capacitors should be connected as close as possible to the IGBT driver.

3. To ensure the high peak gate current, the filter capacitors should be electrolytic capacitor and ceramic capacitor collocation.

4. The output average power of the IGBT driver should be less than the output power of DC-DC module.

EMC solution-recommended circuit(QAW02)



Fig. 4

Parameters	QAW01	QAW02
FUSE	Choose according to	practical input current
MOV	\$14K25	S14K35
CO	680µF/25V	330µF/50V
C1, C2	4.7µF	-/50V
C3, C4	Refer to the	Cout in Fig.2
LCM	1mH	3.3mH
Module		FT-AX1D

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- 3. The product does not support output in parallel with power per liter or hot-swappable use
- 4. For more information please find the application notes on www.mornsun-power.com

Dimensions and Recommended Layout



Pin diameter tolerances :±0.10[±0.004] General tolerances:±0.50[±0.020]

Unit :mm[inch]



Note:Grid 2.54*2.54mm

Pin-C	Dut
Pin	Function
2,3	GND
9	0V
11	-Vo
14	+Vo
16	0V
22,23	Vin

Notes:

- 1. Packing Information please refer to 'Product Packing Information'. Packing bag number: 58200013;
- 2. The lead connecting the power supply module and IGBT driver should be as short as possible during use;
- 3. The output filtering capacitor should be as close as possible to the power supply module and IGBT driver;
- 4. The peak of the IGBT driver gate drive current is high, so low internal resistance electrolytic capacitor is recommended to be used for the power supply module output filter capacitor;
- 5. The average output power of the driver must be lower than that of the power supply module;
- 6. Consider fixing with glue near the module if being used in vibration occasion;
- 7. The max. capacitive load should be tested within the input voltage range and under full load conditions;
- 8. Unless otherwise specified, data in this datasheet should be tested under the conditions of Ta=25°C, humidity<75% when inputting nominal voltage and outputting rated load;
- 9. All index testing methods in this datasheet are based on our Company's corporate standards;
- 10. The performance indexes of the product models listed in this manual are as above, but some indexes of non-standard model products will exceed the above-mentioned requirements, and please directly contact our technicians for specific information;
- 11. We can provide product customization service;
- 12. Specifications of this product are subject to changes without prior notice.

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